BLC9H10XS-350A

Power LDMOS transistor

Rev. 2 — 13 July 2018

AMPLEON

Product data sheet

1. Product profile

1.1 General description

350 W LDMOS packaged asymmetric Doherty power transistor for base station applications at frequencies from 617 MHz to 960 MHz.

Table 1. Typical performance 630 MHz

Typical RF performance at T_{case} = 25 °C in an asymmetrical Doherty test circuit. V_{DS} = 50 V; I_{Dq} = 400 mA (main); $V_{GS(amp)peak}$ = 0.8 V, unless otherwise specified.

Test signal	f	V_{DS}	$P_{L(AV)}$	G_p	η_D	ACPR
	(MHz)	(V)	(dBm)	(dB)	(%)	(dBc)
1-carrier W-CDMA	617 to 652	50	48	19.5	54.7	–26.7 [1]

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.6 dB at 0.01% probability on CCDF.

Table 2. Typical performance 720 MHz

Typical RF performance at T_{case} = 25 °C in an asymmetrical Doherty demo circuit. V_{DS} = 46 V; I_{Dq} = 250 mA (main); $V_{GS(amp)peak}$ = 0.5 V, unless otherwise specified.

Test signal	f	V_{DS}	$P_{L(AV)}$	G_p	η_D	ACPR
	(MHz)	(V)	(dBm)	(dB)	(%)	(dBc)
1-carrier W-CDMA	717 to 728	46	47.5	18.9	55.1	–29.6 [1]

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.6 dB at 0.01% probability on CCDF.

Table 3. Typical performance 880 MHz

Typical RF performance at T_{case} = 25 °C in an asymmetrical Doherty production test circuit. V_{DS} = 50 V; I_{Dq} = 400 mA (main); $V_{GS(amp)peak}$ = 0.55 V, unless otherwise specified.

Test signal	f	V_{DS}	$P_{L(AV)}$	G_p	η_D	ACPR
	(MHz)	(V)	(dBm)	(dB)	(%)	(dBc)
1-carrier W-CDMA	869 to 894	50	48	18.3	54	–31.0 [1]

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.6 dB at 0.01% probability on CCDF.

Table 4. Typical performance 940 MHz

Typical RF performance at T_{case} = 25 °C in an asymmetrical Doherty test circuit. V_{DS} = 50 V; I_{Dq} = 450 mA (main); $V_{GS(amp)peak}$ = 0.65 V, unless otherwise specified.

Test signal	f	V_{DS}	$P_{L(AV)}$	G_p	η_D	ACPR
	(MHz)	(V)	(dBm)	(dB)	(%)	(dBc)
1-carrier W-CDMA	925 to 960	50	48	19	53.5	–30.9 [1]

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.6 dB at 0.01% probability on CCDF.

1.2 Features and benefits

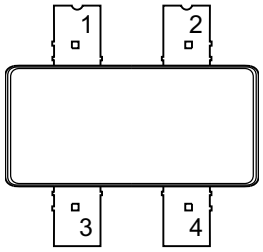
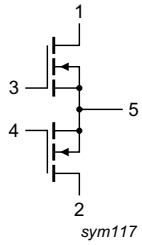
- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internal integrated wideband input matching for ease of use
- Integrated ESD protection
- For RoHS compliance see the product details on the Ampleon website

1.3 Applications

- RF power amplifiers for base stations and multi carrier applications in the 617 MHz to 960 MHz frequency range

2. Pinning information

Table 5. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain1		
2	drain2		
3	gate1		
4	gate2		
5	source [1]		

[1] Connected to flange.

3. Ordering information

Table 6. Ordering information

Type number	Package		
	Name	Description	Version
BLC9H10XS-350A	-	air cavity plastic earless flanged package; 4 leads	SOT1273-1

4. Limiting values

Table 7. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	105	V
$V_{GS(amp)main}$	main amplifier gate-source voltage		–6	+11	V
$V_{GS(amp)peak}$	peak amplifier gate-source voltage		–6	+11	V

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Table 7. Limiting values *...continued*

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature	[1]	-	225	°C
T_{case}	case temperature	operating [1]	–40	+125	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 8. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	V_{DS} = 50 V; I_{Dq} = 400 mA (main); $V_{GS(amp)peak}$ = 0.55 V; T_{case} = 80 °C		
		P_L = 63 W	0.4	K/W
		P_L = 80 W	0.384	K/W

6. Characteristics

Table 9. DC characteristics

T_j = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Main device						
$V_{(BR)DSS}$	drain-source breakdown voltage	V_{GS} = 0 V; I_D = 1 mA	108	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_D = 100 mA	1.5	2.0	2.5	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 50 V; I_D = 400 mA	1.71	2.28	2.86	V
I_{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 50 V	-	-	1.4	µA
I_{DSX}	drain cut-off current	V_{GS} = $V_{GS(th)}$ + 3.75 V; V_{DS} = 10 V	-	16.5	-	A
I_{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	140	nA
g_{fs}	forward transconductance	V_{DS} = 10 V; I_D = 5 A	-	6.7	-	S
$R_{DS(on)}$	drain-source on-state resistance	V_{GS} = $V_{GS(th)}$ + 3.75 V; I_D = 3.5 A	-	238	300	mΩ
Peak device						
$V_{(BR)DSS}$	drain-source breakdown voltage	V_{GS} = 0 V; I_D = 1.5 mA	108	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_D = 150 mA	1.5	2.0	2.5	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 50 V; I_D = 600 mA	1.71	2.28	2.86	V
I_{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 50 V	-	-	1.4	µA
I_{DSX}	drain cut-off current	V_{GS} = $V_{GS(th)}$ + 3.75 V; V_{DS} = 10 V	-	24.5	-	A
I_{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	140	nA
g_{fs}	forward transconductance	V_{DS} = 10 V; I_D = 7.50 A	-	9.9	-	S
$R_{DS(on)}$	drain-source on-state resistance	V_{GS} = $V_{GS(th)}$ + 3.75 V; I_D = 5.25 A	-	161	203	mΩ

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Table 10. RF characteristics

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 - 64 DPCH; f_1 = 871.5 MHz; f_2 = 891.5 MHz; RF performance at V_{DS} = 50 V; I_{Dq} = 400 mA (main); $V_{GS(amp)peak}$ = 0.55 V; T_{case} = 25 °C; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 869 MHz to 894 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	$P_{L(AV)}$ = 63 W	17	18.1	-	dB
RL_{in}	input return loss	$P_{L(AV)}$ = 63 W	-	−18.2	−11.5	dB
η_D	drain efficiency	$P_{L(AV)}$ = 63 W	50	54	-	%
ACPR	adjacent channel power ratio	$P_{L(AV)}$ = 63 W	-	−31	−24	dBc

Table 11. RF characteristics

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 - 64 DPCH; f = 891.5 MHz; RF performance at V_{DS} = 50V; I_{Dq} = 400 mA (main); $V_{GS(amp)peak}$ = 0.55 V; T_{case} = 25 °C; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 869 MHz to 894 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
PAR_O	output peak-to-average ratio	$P_{L(AV)}$ = 90 W	5.9	6.6	-	dB
$P_{L(M)}$	peak output power	$P_{L(AV)}$ = 90 W	343	415	-	W

7. Test information

7.1 Ruggedness in Doherty operation

The BLC9H10XS-350A is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 52 V; I_{Dq} = 400 mA; $V_{GS(amp)peak}$ = 0.55 V; f = 881 MHz; P_L = 140 W (5 dB OBO); pulsed CW (t_p = 100 μs; δ = 10 %).

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7.2 Impedance information

Table 12. Typical impedance of main device

Measured load-pull data of main device; I_{Dq} = 400 mA (main); V_{DS} = 50 V; pulsed CW (t_p = 100 µs; δ = 10 %).

f	Z_S [1]	Z_L [1]	P_L [2]	η_D [2]	G_p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
Maximum power load					
600	8.0 – j4.2	3.2 + j1.3	237.9	66.6	17.9
698	5.9 – j3.0	3.1 + j1.2	236.0	68.0	19.0
746	5.1 – j3.8	3.0 + j1.2	240.1	70.1	19.3
769	4.9 – j4.3	2.3 + j1.0	238.9	65.2	18.5
800	4.7 – j5.1	2.3 + j1.0	236.5	67.2	19.2
820	4.7 – j5.6	2.7 + j0.9	234.5	66.7	18.8
869	5.0 – j7.1	2.7 + j0.9	227.8	68.4	19.1
880	5.1 – j7.4	2.7 + j0.9	231.1	69.4	19.0
894	5.3 – j7.8	2.7 + j0.9	228.0	69.6	19.0
925	5.9 – j8.8	2.0 + j0.8	229.4	66.8	18.2
942	6.4 – j9.5	2.9 + j0.1	231.6	63.2	17.7
960	6.9 – j10.0	2.9 + j0.1	232.3	63.9	17.6
Maximum drain efficiency load					
600	7.9 – j3.4	2.7 + j4.5	129.7	79.0	20.9
698	5.7 – j2.8	2.9 + j3.1	176.3	76.7	20.9
746	4.7 – j3.6	2.2 + j3.6	136.9	78.9	21.8
769	4.6 – j4.2	2.1 + j3.6	131.0	78.1	21.6
800	4.5 – j4.9	2.2 + j2.6	173.6	77.3	21.3
820	4.5 – j5.5	2.5 + j2.9	158.2	76.0	21.2
869	4.8 – j7.0	2.6 + j3.0	148.0	75.4	21.4
880	4.9 – j7.2	1.9 + j2.4	160.4	77.3	20.8
894	5.1 – j7.6	1.9 + j2.5	152.3	76.3	21.0
925	5.5 – j8.3	1.9 + j2.5	151.9	79.4	21.0
942	6.0 – j9.2	2.0 + j2.5	145.7	79.1	21.0
960	6.5 – j9.7	2.0 + j2.5	140.4	78.3	20.9

[1] Z_S and Z_L defined in Figure 1.

[2] At 3 dB gain compression.

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Table 13. Typical impedance of peak device

Measured load-pull data of peak device; I_{Dq} = 600 mA (peak); V_{DS} = 50 V; pulsed CW (t_p = 100 µs; δ = 10 %).

f	Z_S [1]	Z_L [1]	P_L [2]	η_D [2]	G_p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
Maximum power load					
600	5.8 – j1.8	2.6 + j0.4	360.7	69.0	19.0
698	3.7 – j2.3	2.0 + j0.2	347.3	65.0	19.4
746	3.4 – j3.2	2.0 + j0.2	361.1	69.0	19.6
769	3.4 – j3.7	1.9 + j0.3	358.3	70.5	19.5
800	3.5 – j4.3	2.0 – j0.3	352.1	64.0	19.1
820	3.5 – j4.3	2.0 – j0.1	349.2	66.0	19.0
869	3.6 – j4.7	2.0 + j0.0	347.3	67.0	18.8
880	4.4 – j5.8	2.0 + j0.0	335.5	69.5	19.1
925	5.2 – j6.5	2.0 – j0.7	329.7	60.9	17.9
942	6.1 – j6.9	2.0 – j0.7	337.1	62.8	17.9
960	6.7 – j6.9	2.0 – j0.7	338.1	63.4	17.8
Maximum drain efficiency load					
600	5.5 – j1.4	2.3 + j2.7	224.5	80.6	21.6
698	3.6 – j2.2	2.2 + j1.6	270.9	76.6	21.4
746	3.2 – j3.1	1.8 + j2.2	202.8	78.9	22.4
769	3.3 – j3.5	2.1 + j1.6	249.6	77.9	21.6
800	3.3 – j4.0	1.6 + j1.4	240.2	77.3	22.0
820	3.2 – j4.1	1.4 + j1.9	182.7	78.4	22.5
869	3.5 – j4.5	1.7 + j1.4	246.3	77.6	21.1
880	4.2 – j5.6	1.7 + j1.4	213.8	76.3	21.4
925	4.9 – j6.1	1.2 + j1.2	186.7	74.6	21.4
942	5.7 – j6.4	1.2 + j1.2	177.3	77.4	21.8
960	6.5 – j6.6	1.4 + j0.7	247.8	77.2	20.5

[1] Z_S and Z_L defined in Figure 1.

[2] At 3 dB gain compression.

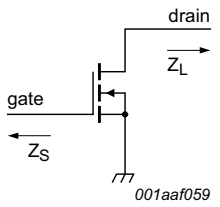


Fig 1. Definition of transistor impedance

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7.3 Recommended impedances for Doherty design

Table 14. Typical impedance of main at 1 : 1 load

Measured load-pull data of main device; I_{Dq} = 400 mA (main); V_{DS} = 50 V; pulsed CW (t_p = 100 µs; δ = 10 %).

f	Z_S [1]	Z_L [1]	$P_{L(3dB)}$	η_D [2]	G_p [2]
(MHz)	(Ω)	(Ω)	(dBm)	(%)	(dB)
600	8.0 – j4.2	3.1 + j2.1	53.6	40.7	21.6
698	5.9 – j3.0	3.1 + j1.9	53.5	40.1	22.4
746	5.1 – j3.8	2.8 + j1.9	53.5	41.3	22.7
769	4.9 – j4.3	2.6 + j1.8	53.5	40.1	22.7
800	4.7 – j5.1	2.7 + j1.5	53.6	41.0	22.8
820	4.7 – j5.6	2.7 + j1.5	53.5	41.5	22.6
869	5.0 – j7.1	2.8 + j1.2	53.5	42.9	22.7
880	5.1 – j7.4	2.8 + j1.2	53.5	42.6	22.6
894	5.3 – j7.8	2.8 + j1.2	53.5	43.2	22.6
925	5.9 – j8.8	2.5 + j1.2	53.5	43.5	22.6
942	6.4 – j9.5	2.5 + j1.2	53.5	43.6	22.6
960	6.9 – j10.0	2.5 + j1.2	53.5	42.7	22.5

[1] Z_S and Z_L defined in Figure 1.

[2] At $P_{L(AV)}$ = 63 W.

Table 15. Typical impedance of main device at 1 : 2.5 load

Measured load-pull data of main device; I_{Dq} = 400 mA (main); V_{DS} = 50 V; pulsed CW (t_p = 100 µs; δ = 10 %).

f	Z_S [1]	Z_L [1]	$P_{L(3dB)}$	η_D [2]	G_p [2]
(MHz)	(Ω)	(Ω)	(dBm)	(%)	(dB)
600	7.9 – j3.4	3.0 + j4.9	50.7	60.9	24.1
698	5.7 – j2.8	3.1 + j4.9	50.6	59.5	24.9
746	4.7 – j3.6	2.9 + j4.6	50.5	61.3	25.1
769	4.6 – j4.2	2.7 + j4.2	50.7	60.7	24.7
800	4.5 – j4.9	2.5 + j3.9	50.7	61.2	25.4
820	4.5 – j5.5	2.5 + j3.9	50.6	62.5	24.9
869	4.8 – j7.0	2.5 + j3.9	50.5	62.4	24.9
880	4.9 – j7.2	2.5 + j3.9	50.4	61.6	24.9
894	5.1 – j7.6	2.5 + j3.9	50.3	61.7	24.8
925	5.5 – j8.3	2.3 + j3.6	50.4	62.9	25.1
942	6.0 – j9.2	2.2 + j3.4	50.4	63.4	25.1
960	6.5 – j9.7	2.1 + j3.4	50.4	63.2	24.5

[1] Z_S and Z_L defined in Figure 1.

[2] At $P_{L(AV)}$ = 63 W.

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Table 16. Typical impedance of peak device at 1 : 1 load

Measured load-pull data of peak device; I_{Dq} = 600 mA (peak); V_{DS} = 50 V; pulsed CW (t_p = 100 µs; δ = 10 %).

f	Z_S [1]	Z_L [1]	$P_{L(3dB)}$	η_D [2]	G_p [2]
(MHz)	(Ω)	(Ω)	(dBm)	(%)	(dB)
600	5.8 – j1.8	2.6 + j1.1	55.3	35.0	22.9
698	3.7 – j2.3	2.3 + j0.8	55.2	34.8	23.3
720	3.4 – j3.2	2.3 + j0.8	55.2	35.0	23.4
769	3.4 – j4.3	2.3 + j0.5	55.2	34.4	23.1
800	3.5 – j4.4	2.1 + j0.5	55.2	34.7	23.5
820	3.5 – j4.7	2.1 + j0.6	55.2	34.5	22.7
869	3.6 – j5.8	1.9 + j0.2	55.2	35.4	22.9
880	4.4 – j5.9	1.9 + j0.3	55.2	35.8	23.0
894	4.4 – j6.5	1.8 + j0.3	55.2	35.1	22.8
925	5.2 – j6.9	1.7 + j0.1	55.2	34.2	22.5
942	6.1 – j6.9	1.7 + j0.0	55.2	35.0	22.7
960	6.7 – j6.9	1.7 + j0.0	55.2	35.8	22.7

[1] Z_S and Z_L defined in Figure 1.

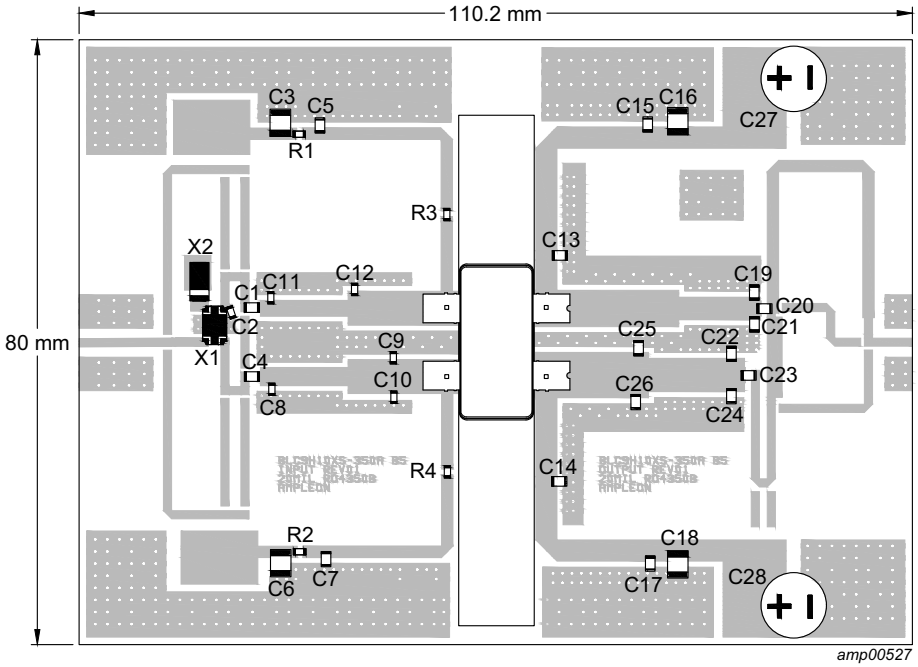
[2] At $P_{L(AV)}$ = 63 W.

Table 17. Off-state impedances of peak device

f	Z_{off}
(MHz)	(Ω)
600	0.15 – j5.79
698	0.15 – j4.54
720	0.14 – j4.32
769	0.12 – j3.91
800	0.10 – j3.45
820	0.10 – j3.37
869	0.10 – j2.88
880	0.10 – j2.86
894	0.09 – j2.70
925	0.09 – j2.56
942	0.09 – j2.42
960	0.09 – j2.27

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7.4 Test circuit



Printed-Circuit Board (PCB): RO4350B: ε_r = 3.66; thickness = 0.508 mm; thickness copper plating = 35 μm. See Table 18 for a list of components.

Fig 2. Component layout

Table 18. List of components

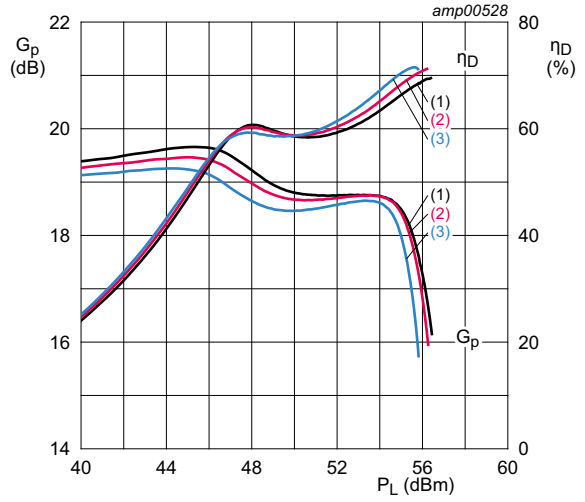
See Figure 2 for component layout.

Component	Description	Value	Remarks
C1, C4, C5, C7,C15, C17, C23	multilayer ceramic chip capacitor	100 pF	Murata: Hi-Q SMD 0805
C2, C8	multilayer ceramic chip capacitor	2.0 pF	
C3, C6, C16, C18	multilayer ceramic chip capacitor	4.7 μF	Murata: GRM32ER71H475KA88L
C9, C10, C12	multilayer ceramic chip capacitor	4.3 pF	
C11	multilayer ceramic chip capacitor	2.7 pF	
C13, C14	multilayer ceramic chip capacitor	47 pF	
C19	multilayer ceramic chip capacitor	3.3 pF	
C20	multilayer ceramic chip capacitor	22 pF	
C21	multilayer ceramic chip capacitor	3.0 pF	
C22, C24	multilayer ceramic chip capacitor	2.4 pF	
C25	multilayer ceramic chip capacitor	6.8 pF	
C26	multilayer ceramic chip capacitor	5.6 pF	
C27, C28	electrolytic capacitor	470 μF, 63 V	
R1, R2, R3, R4	resistor	4.7 Ω, 1 %	SMD 0805
X1	hybrid coupler	3 dB	Anaren: X3C07F1-02S
X2	termination	50 Ω	Anaren: C16A50Z4

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7.5 Graphical data

7.5.1 Pulsed CW



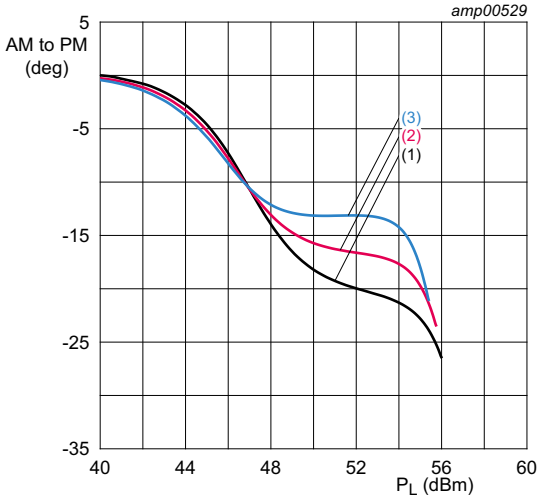
V_{DS} = 50 V; I_{Dq} = 380 mA; $V_{GS(amp)peak}$ = 0.55 V; t_p = 100 μs; δ = 10 %.

(1) f = 869 MHz

(2) f = 881 MHz

(3) f = 894 MHz

Fig 3. Power gain and drain efficiency as function of output power; typical values



V_{DS} = 50 V; I_{Dq} = 380 mA; $V_{GS(amp)peak}$ = 0.55 V; t_p = 100 μs; δ = 10 %.

(1) f = 869 MHz

(2) f = 881 MHz

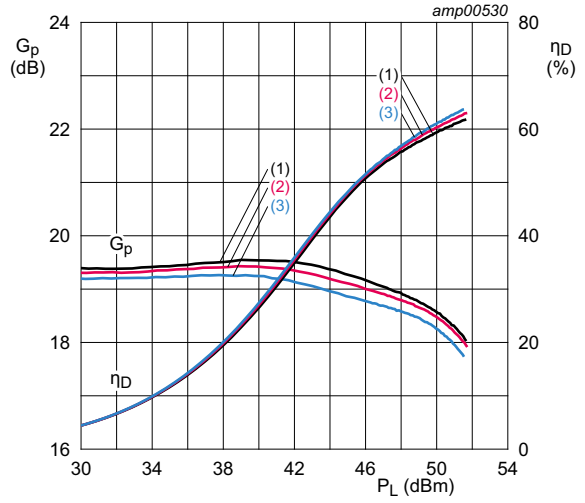
(3) f = 894 MHz

Fig 4. Normalized AM to PM as a function of output power; typical values

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7.5.2 1-Carrier W-CDMA

Test signal: 3GPP test model 1; 1 to 64 DPCH (100 % clipping): PAR = 9.6 dB at 0.01 % probability on CCDF.



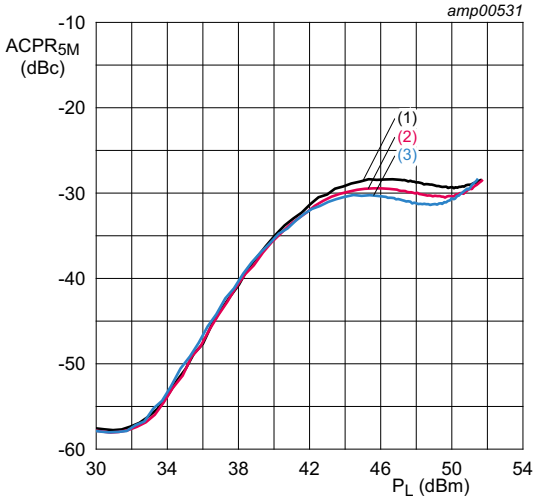
V_{DS} = 50 V; I_{Dq} = 380 mA; $V_{GS(amp)peak}$ = 0.55 V.

(1) f = 869 MHz

(2) f = 881 MHz

(3) f = 894 MHz

Fig 5. Power gain and drain efficiency as function of output power; typical values



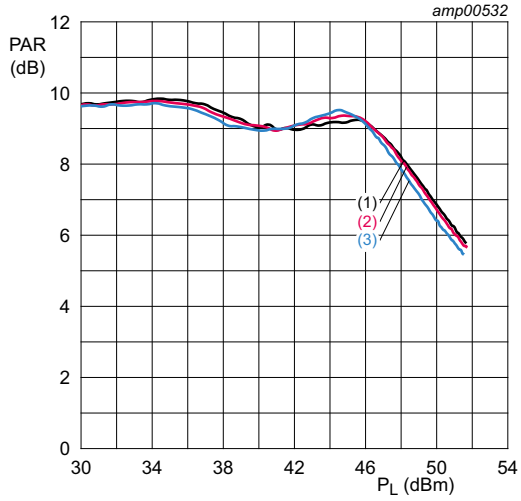
V_{DS} = 50 V; I_{Dq} = 380 mA; $V_{GS(amp)peak}$ = 0.55 V.

(1) f = 869 MHz

(2) f = 881 MHz

(3) f = 894 MHz

Fig 6. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



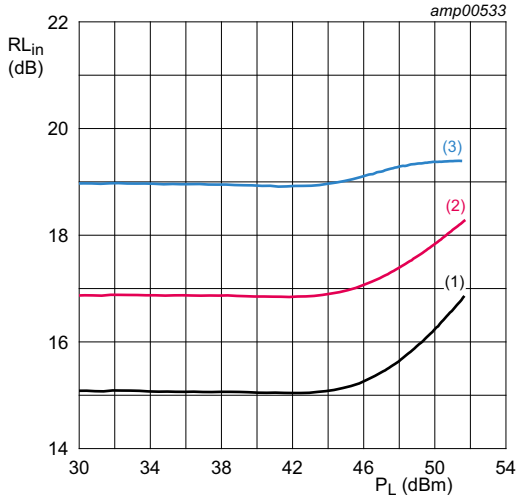
V_{DS} = 50 V; I_{Dq} = 380 mA; $V_{GS(amp)peak}$ = 0.55 V.

(1) f = 869 MHz

(2) f = 881 MHz

(3) f = 894 MHz

Fig 7. Peak-to-average power ratio as a function of output power; typical values



V_{DS} = 50 V; I_{Dq} = 380 mA; $V_{GS(amp)peak}$ = 0.55 V.

(1) f = 869 MHz

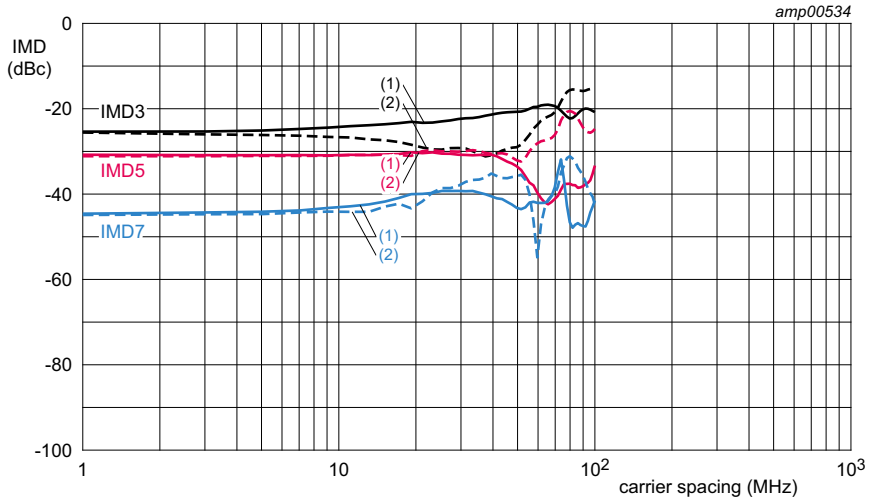
(2) f = 881 MHz

(3) f = 894 MHz

Fig 8. Input return loss as a function of output power; typical values

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7.5.3 2-Tone VBW



V_{DS} = 50 V; I_{Dq} = 380 mA; $V_{GS(amp)peak}$ = 0.55 V; f_c = 881 MHz.

(1) IMD low

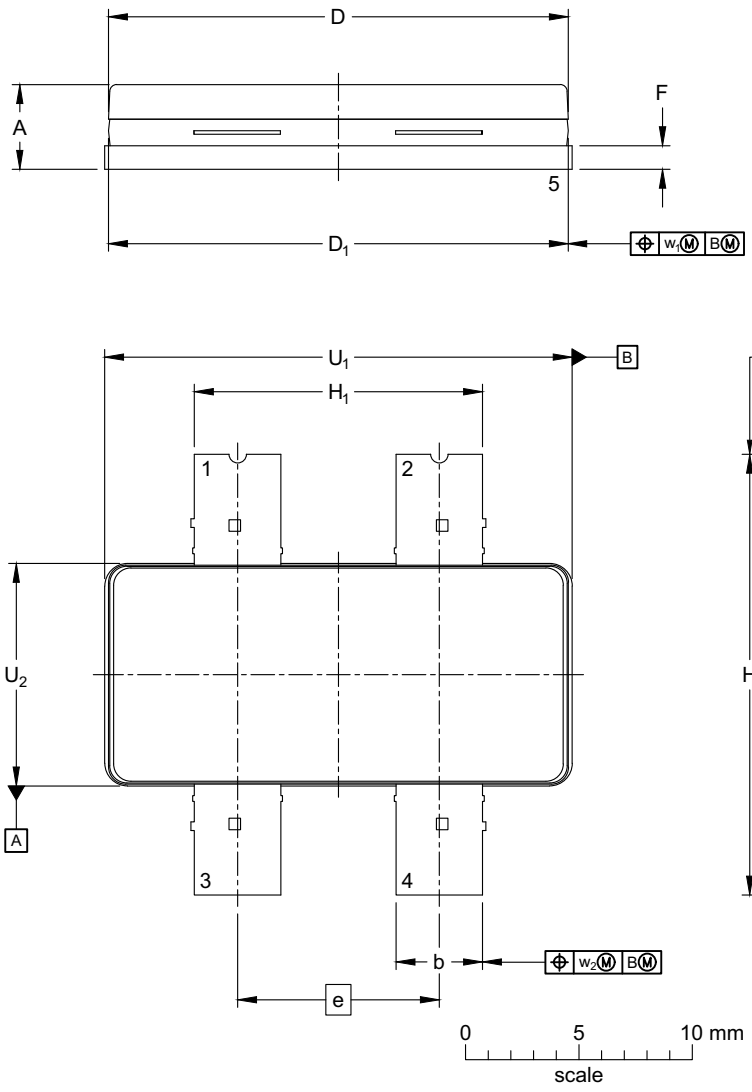
(2) IMD high

Fig 9. VBW capability in Doherty demo board

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8. Package outline

Air cavity plastic earless flanged package; 4 leads SOT1273-1



Dimensions

Unit		A	b	c	D	D_1	E	E_1	e	F	H	H_1	$Q^{(1)}$	U_1	U_2	v	w_1	w_2	y
mm	max	4.01	3.91	0.18	20.42	20.37	9.80	9.75		1.14	19.53	12.83	1.68	20.70	9.91	0.50	0.50	0.50	0.10
	nom								8.89										
	min	3.40	3.71	0.13	20.12	20.17	9.50	9.55		0.94	19.33	12.57	1.45	20.50	9.70				

Note:
1. Dimension Q is measured at 0.1 mm away from the flange.
2. Ringframe and/or ringframe glue shall not overhang at the side of the flange.

sot1273-1_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1273-1						17-01-12

Fig 10. Package outline SOT1273-1

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9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

Table 19. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C3 [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

[1] CDM classification C3 is granted to any part that passes after exposure to an ESD pulse of ≥ 1000 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

10. Abbreviations

Table 20. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
OBO	Output Back Off
MTF	Median Time to Failure
PAR	Peak-to-Average Ratio
RoHS	Restriction of Hazardous Substances
SMD	Surface Mounted Device
VBW	Video Bandwidth
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

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11. Revision history

Table 21. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLC9H10XS-350A v.2	20180713	Product data sheet	-	BLC9H10XS-350A v.1
Modifications	• Section 1.1 on page 1: changed value PAR • Table 8 on page 3: changed conditions P_L • Table 10 on page 4: changed description • Table 11 on page 4: changed description • Section 7.3 on page 7: changed unit of $P_{L(3dB)}$			
BLC9H10XS-350A v.1	20180518	Product data sheet	-	-

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12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 13 July 2018
Document identifier: BLC9H10XS-350A

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